### 3.2x1.6mm INFRARED EMITTING DIODE

Part Number: AP3216SF4C

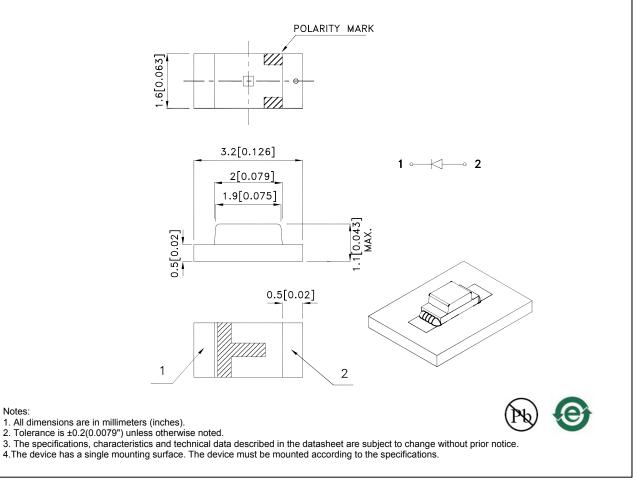
#### Features

- 3.2mmx1.6mm SMT LED, 1.1mm thickness.
- Mechanically and spectrally matched to the phototransistor.
- Wide viewing angle.
- Package : 2000pcs / reel.
- Moisture sensitivity level : level 3.
- RoHS compliant.

#### Description

SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes.

#### **Package Dimensions**



SPEC NO: DSAA8461 APPROVED: WYNEC REV NO: V.8B CHECKED: Allen Liu DATE: Mar/02/2015 DRAWN: Q.M.Chen PAGE: 1 OF 5 ERP: 1203000401

### Selection Guide

| Part No.   | Dice         | Lens Type   | Po (mW/sr) [2]<br>@ 20mA |      | Viewing<br>Angle [1] |
|------------|--------------|-------------|--------------------------|------|----------------------|
|            |              |             | Min.                     | Тур. | 201/2                |
| AP3216SF4C | SF4 (GaAlAs) | Water Clear | 0.8                      | 1.5  | 120°                 |

Notes:
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. \*Radiant intensity with asterisk is measured at 50mA;Radiant Intensity/ luminous flux: +/-15%.
3. Radiant intensity value is traceable to the CIE127-2007 compliant national standards.

### Electrical / Optical Characteristics at TA=25°C

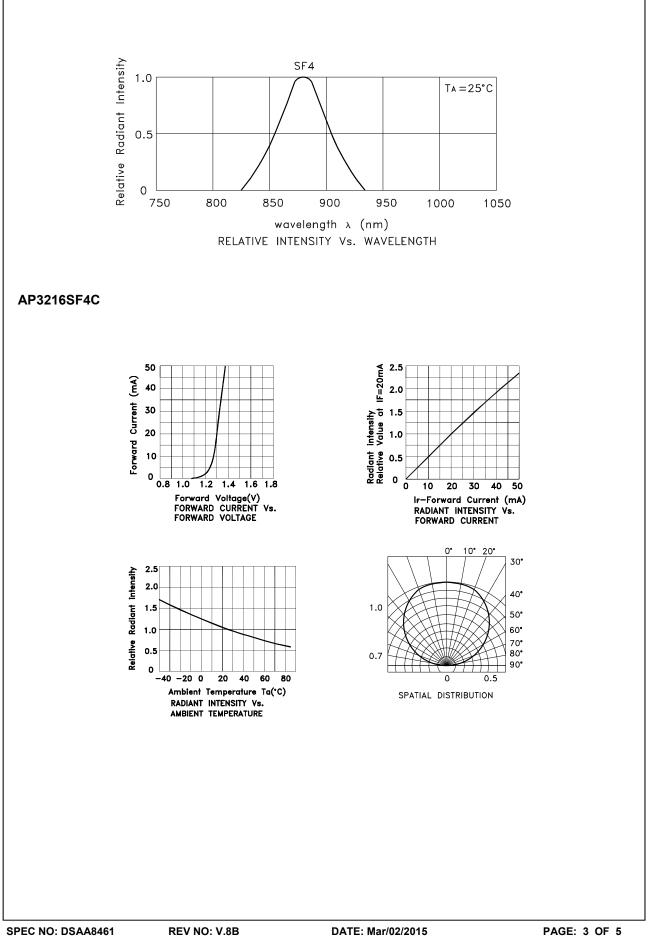
| Parameter                | P/N | Symbol | Тур. | Max. | Units | Test Conditions |
|--------------------------|-----|--------|------|------|-------|-----------------|
| Forward Voltage [1]      | SF4 | VF     | 1.3  | 1.6  | V     | I⊧=20mA         |
| Reverse Current          | SF4 | lr     |      | 10   | uA    | VR = 5V         |
| Capacitance              | SF4 | С      | 90   |      | pF    | VF=0V;f=1MHz    |
| Peak Spectral Wavelength | SF4 | λP     | 880  |      | nm    | I⊧=20mA         |
| Spectral Bandwidth       | SF4 | Δλ1/2  | 50   |      | nm    | I⊧=20mA         |

Forward Voltage: +/-0.1V.
 Wavelength value is traceable to the CIE127-2007 compliant national standards.
 Excess driving current and/or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

### Absolute Maximum Ratings at TA=25°C

| Parameter                | Symbol | SF4        | Units |
|--------------------------|--------|------------|-------|
| Power dissipation        | Po     | 80         | mW    |
| DC Forward Current       | lF     | 50         | mA    |
| Peak Forward Current [1] | ifs    | 1.2        | А     |
| Reverse Voltage          | VR     | 5          | V     |
| Operating Temperature    | Та     | -40 To +85 | °C    |
| Storage Temperature      | Тятд   | -40 To +85 | °C    |

Note: 1. 1/100 Duty Cycle, 10µs Pulse Width.

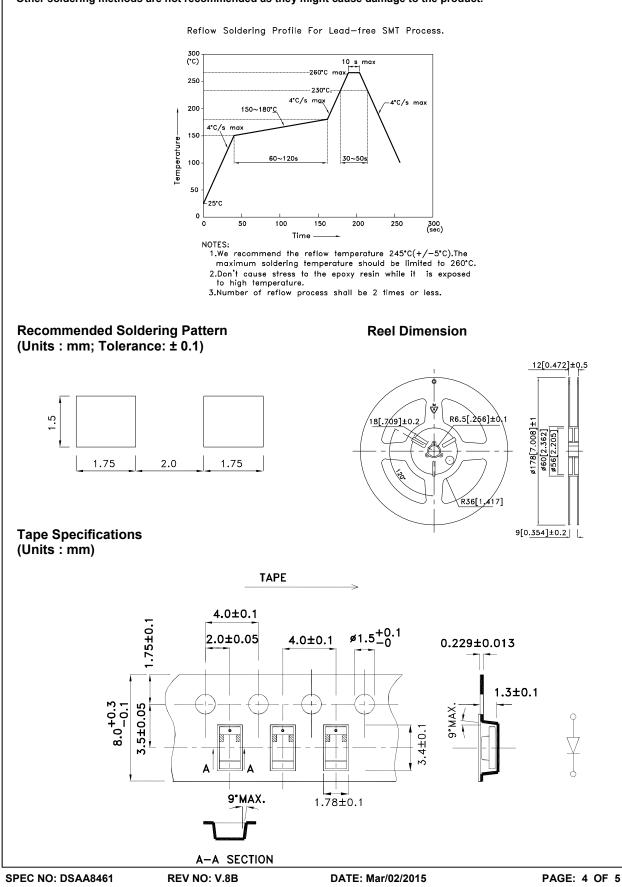


## AP3216SF4C

**APPROVED: WYNEC** 

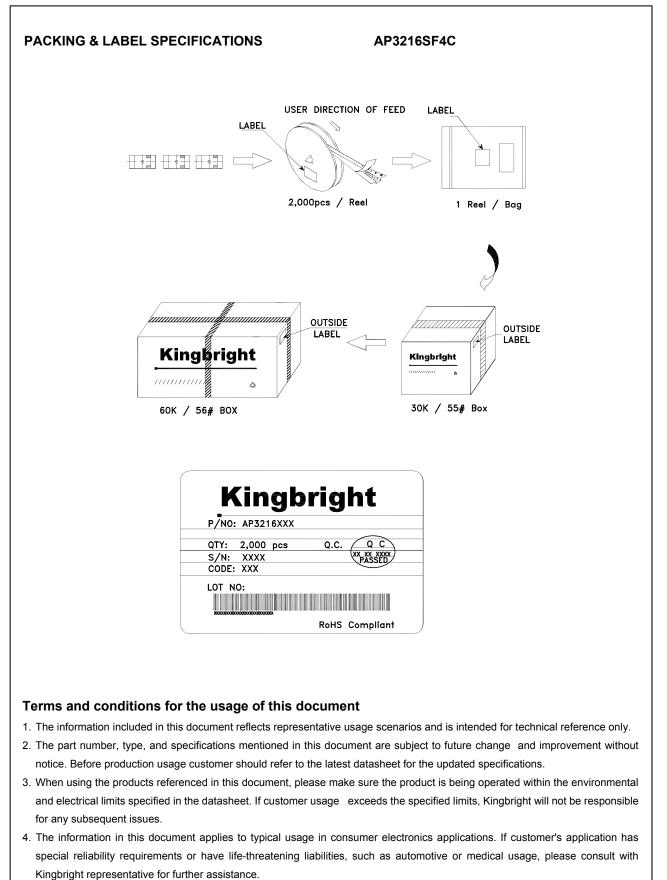
**CHECKED: Allen Liu** 

Reflow soldering is recommended and the soldering profile is shown below. Other soldering methods are not recommended as they might cause damage to the product.



DRAWN: Q.M.Chen

ERP: 1203000401



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- 6. All design applications should refer to Kingbright application notes available at http://www.KingbrightUSA.com/ApplicationNotes

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